

EMN Epitaxy 2019

June 17 to 21 Amsterdam, the Netherlands

Dear colleagues,

It is our great pleasure to announce the **2019 Energy, Materials, and Nanotechnology (EMN) Meeting on Epitaxy, which will take place in Amsterdam, the Netherlands from June 17th till June 21st, 2019**. The EMN Meetings grew out of a small workshop series that began in 2008 at a traditional villa in Orlando, Florida. Over the next three years, six additional successful workshops were organized on various focus topics in materials science, and grouped under the title of “Villa Conference” in honor of the original 2008 Orlando meeting. The Villa Conference series has grown rapidly beyond the traditional villa setting, continuing to attract highly-quality contributions from members of the international scientific and engineering communities. In 2012 the first Conference with a broader theme of Energy, Materials and Nanotechnology was held. The EMN Meetings now include five annual gatherings: EMN Fall (Orlando), EMN Spring (Las Vegas), EMN Summer (Cancun), EMN East (Beijing), and EMN Open (Chengdu).

We invite all members of the international scientific community interested in new developments in Epitaxy to attend and to submit their latest findings to EMN Meeting on Epitaxy 2019. The conference will provide a range of **oral** and **poster presentations** and **invited talks**.

Selected (after peer-review) papers from the conference will be published in various ISI and Scopus indexed journals (**Nanoscale Research Letters**, **Journal of Semiconductors** and **OAHOST** which is a new journal open for submissions on August 2016. *OAHOST is a peer-reviewed, open access journal publishing quality research papers across all disciplines, which means that all published articles are made freely available online without a subscription, and authors retain the copyright of their work. For EMN articles published the author publication fee will be waived, the EMN will pay to make the article open access as long as the manuscript can go through the peer-review organized by EMN publication committee. OAHOST is open to both original research articles as well as review articles*). Only one paper per registered participant will be published.

We cordially invite you to attend the conference, actively participate in its technical sessions, and contribute to the continued success of this conference series. Up-to-date information on all aspects of the conference will appear soon on the conference webpage: <http://emnmeeting.org/2019-epitaxy/>.

The conference will tentatively cover the following topics (conference’s topics):

- ❖ EMN Epitaxy on Molecular Beam Epitaxy
- ❖ EMN Epitaxy on Metal-organic Chemical Vapor Deposition
- ❖ EMN Epitaxy on Epitaxial Growth
- ❖ EMN Epitaxy on Nanomaterials
- ❖ EMN Epitaxy on 2D Semiconducting Materials
- ❖ EMN Epitaxy on Atomic Layer Deposition
- ❖ EMN General Workshop on Epitaxy



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The conference will be held in the **Holiday Inn Amsterdam – Arena Towers**, located at Hoogoorddreef 66, 1101 BE Amsterdam The Netherlands. We invite you all to take part in this exciting and enjoyable Conference, where experts from all over the world will be able share their latest research, and also to give yourself some time for recreational pursuits in the fabulous city site!

Abstract submission already opened (<http://emnmeeting.org/2019-epitaxy/>). Please, follow the same link for further information about the event and preliminary registration. Please spread this information among your colleagues and friends.

If you require any other information (conference venue, accommodation, onsite registration), do not hesitate to contact the Conference Secretariat at the following e-mail address "emn-epitaxy@outlook.com" or visit the website <http://emnmeeting.org/2019-epitaxy/> (abstract submission, proceedings publication, preliminary registration).

We are looking forward to meeting you in Amsterdam!

Kindest regards,

EMN 2019 International Advisory Committees:

Yasuhiko Arakawa, University of Tokyo, Japan

Flemming Besenbacher, Aarhus University, Denmark

Ivan Božović, Brookhaven National Laboratory, United States

Vladimir Fomin, Leibniz Institute for Solid State and Materials Research (IFW) Dresden, Germany

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